

# BRDBC846WS

Rev.B Jul.-2023

DATA SHEET

## / Descriptions

SOT-363 NPN Double silicon NPN transistor in a SOT-363 Plastic Package.

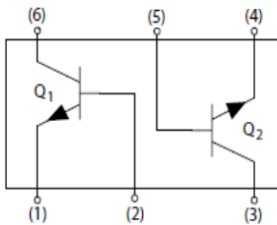
## / Features

, BRDBC856WS  
 High voltage, complementary pair with BRDBC856WS, HF Product.

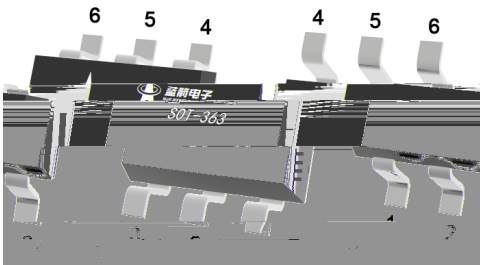
## / Applications

General purpose high voltage amplifier.

## / Equivalent Circuit



## / Pinning



PIN 1 4 Emitter

PIN 2 5 Base

PIN 3 6 Collector

## / hFE Classifications & Marking

h <sub>FE</sub> Classifications Symbol	A	B
h <sub>FE</sub> Range	110 220	200 450
Marking	1A	1B

## / Absolute Maximum Ratings(Ta=25 )

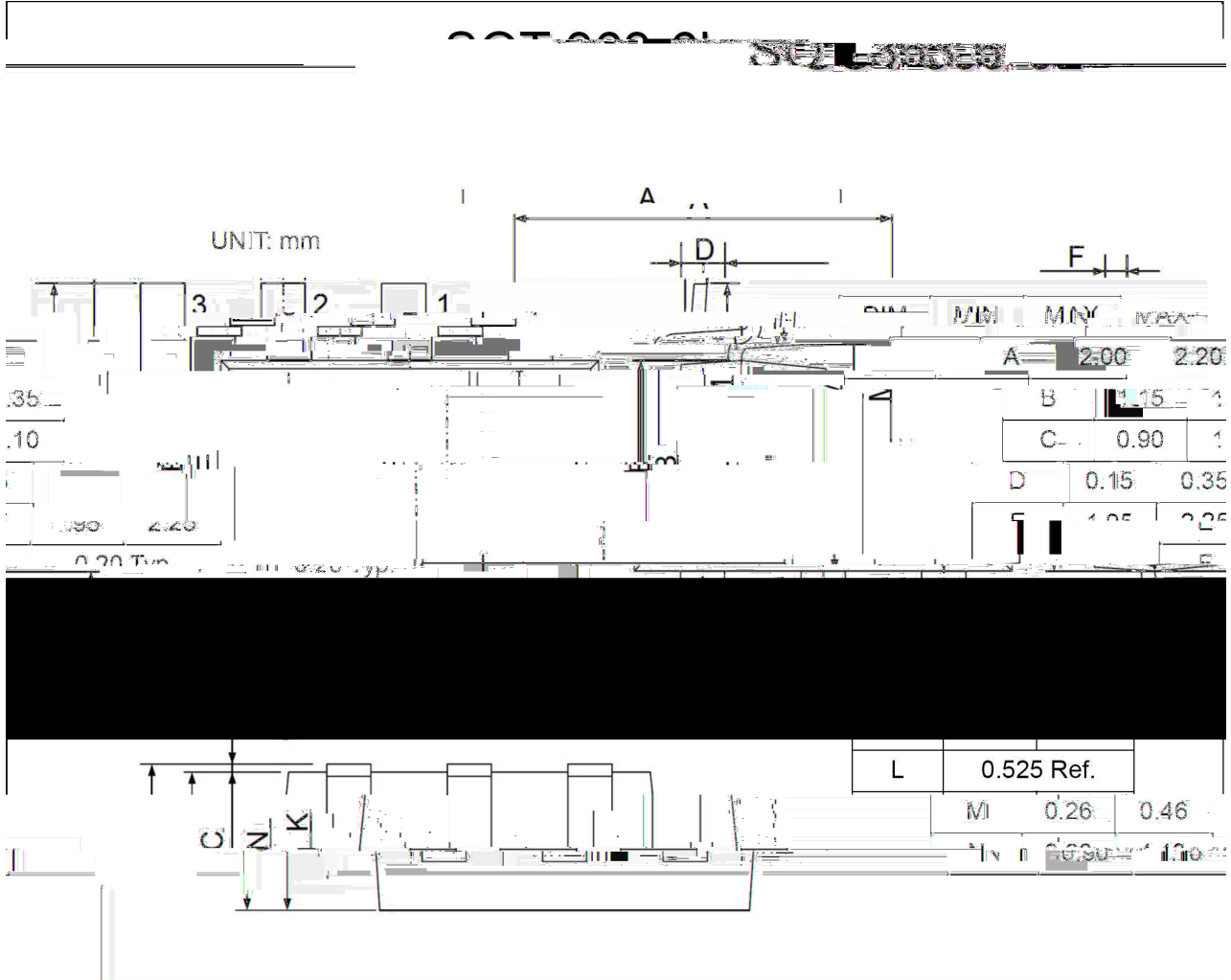
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V <sub>CBO</sub>	80	V
Collector to Emitter Voltage	V <sub>CEO</sub>	65	V
Emitter to Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current - Continuous	I <sub>C</sub>	100	mA
Collector Power Dissipation	P <sub>C</sub>	200	mW
Junction Temperature	T <sub>j</sub>	150	
Storage Temperature Range	T <sub>stg</sub>	-55 150	

## / Electrical Characteristics(Ta=25 )

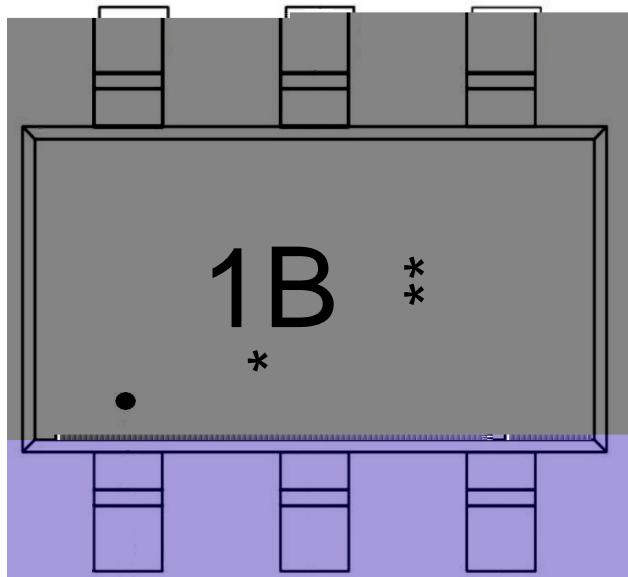
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	V <sub>CBO</sub>	I <sub>C</sub> =10μA I <sub>E</sub> =0	80			V
Collector-Emitter Breakdown Voltage	V <sub>CEO</sub>	I <sub>C</sub> =10mA I <sub>B</sub> = 0	65			V
Emitter-Base Breakdown Voltage	V <sub>EBO</sub>	I <sub>E</sub> =10μA I <sub>C</sub> = 0	6.0			V
Collector Cut-Off Current	I <sub>CBO</sub>	V <sub>CB</sub> =30V I <sub>E</sub> =0			15	nA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V I <sub>C</sub> =0			500	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5.0V I <sub>C</sub> =2.0mA	110		450	
Collector to Emitter Saturation Voltage	V <sub>CE(sat)(1)</sub>	I <sub>C</sub> =10mA I <sub>B</sub> =0.5mA			0.1	V
	V <sub>CE(sat)(2)</sub>	I <sub>C</sub> =100mA I <sub>B</sub> =5.0mA			0.3	V
Base to Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =10mA I <sub>B</sub> =0.5mA		0.77		V
Transition Frequency	f <sub>T</sub>	V <sub>CB</sub> =5.0V I <sub>E</sub> =10mA f=100MHz	100			MHz
Collector Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V I <sub>E</sub> =0 f=1.0MHz			1.5	pF



**/ Package Dimensions**



/ Marking Instructions



● " 1"

1

B h<sub>FE</sub>

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Note:

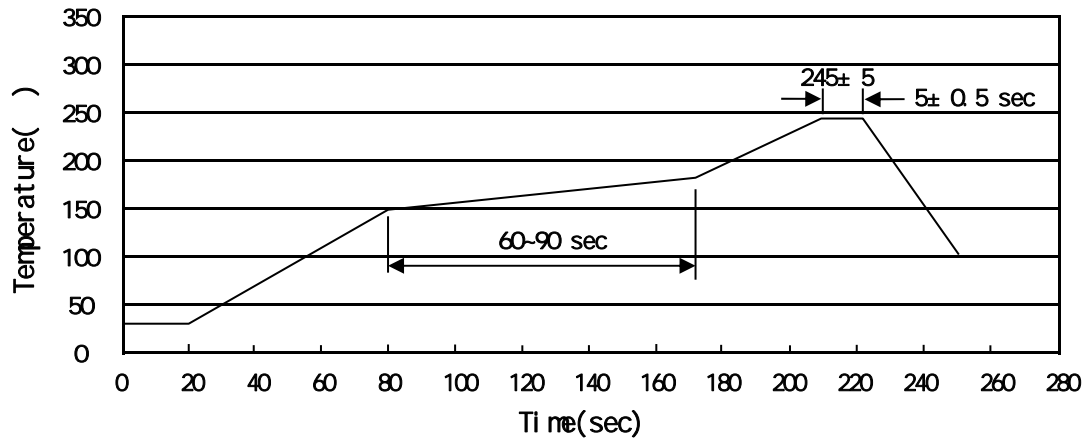
● " 1" Pin

1 Product Type Code

B h<sub>FE</sub> Classifications Symbol Code

\*\*\* Lot No. Code, code change with Lot No

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1            150 180            60 90sec;            1.Preheating:150~180 , Time:60~90sec.
- 2            245±5            5±0.5sec;            2.Peak Temp.:245±5 , Duration:5±0.5sec.
- 3                       2 10 /sec.            3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5            10±1 sec.            Temp.:260±5            Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm <sup>3</sup> )		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
SOT-363	3,000	10	30,000	6	180,000	7 x8	180x120x180	390x385x205

/ Notices